

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2522	nanotube.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/08 13:56
S2	2522	nanotube.ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/08 13:56
S3	193	nanotube.ti.	USPAT	OR	ON	2004/11/08 13:56
S4	413	(977/DIG.1).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/08 14:06
S5	3371	((438/142) or (438/159) or (438/778) or (438/780) or (257/213)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/08 14:08
S6	58731	nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 18:15
S7	3255829	metal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 15:59
S8	1939545	semiconductor or silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 15:59
S9	279	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 15:59
S10	170	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 15:59

S11	20	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near met	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 17:35
S12	26	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near sem	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 17:35
S13	55	((((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near met)) and (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near sem)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 17:35
S14	50	(((((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near met)) and (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near sem)))) and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 17:36
S15	170	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:00
S16	0	(protect\$4 or mask\$4) near2 (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:28

S17	45	(protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:04
S18	39	(dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:01
S19	0	((protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)))) same ((dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:05
S20	3	((protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)))) and ((dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:05
S21	1952582	semiconductor or silicon or semiconduct\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:15

S22	236	(nanotube or nt or cnt or swnt or snt or nt fet or cnt fet or swnt fet or snt fet) near (semiconductor or silicon or semiconduct\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:15
S23	16	met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj nt fet or met adj cnt fet or met adj swnt fet or met adj snt fet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:17
S24	186	(met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj nt fet or met adj cnt fet or met adj swnt fet or met adj snt fet) or ((nanotube or nt or cnt or swnt or snt or nt fet or cnt fet or swnt fet or snt fet) near (metallic or metalic))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:27
S25	45	(protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or nt fet or cnt fet or swnt fet or snt fet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj nt fet or met adj cnt fet or met adj swnt fet or met adj snt fet) or ((nanotube or nt or cnt or swnt or snt or nt fet or cnt fet or swnt fet or snt fet) near (metallic or metalic))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:30
S26	3	(protect\$4 or mask\$4) near4 (((nanotube or nt or cnt or swnt or snt or nt fet or cnt fet or swnt fet or snt fet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj nt fet or met adj cnt fet or met adj swnt fet or met adj snt fet) or ((nanotube or nt or cnt or swnt or snt or nt fet or cnt fet or swnt fet or snt fet) near (metallic or metalic))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:29

S27	3	(selectiv\$4 near2 breakdown\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic))))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:36
S28	3	((protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic)))))) and ((selectiv\$4 near2 breakdown\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic))))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:31
S29	0	(selectiv\$4 near2 dissolv\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic))))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 18:37

S30	2	(selectiv\$4 near2 remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntfet or met adj cntfet or met adj swntfet or met adj sntfet) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 21:54
S31	2	"6325909".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 19:36
S32	1	"20040191157".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 19:36
S33	0	"20040191157".pn. and (substrate or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 19:36
S34	1	"20040191157".pn. and (silicon or semiconductor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 19:37
S35	1	"20040191157".pn. and (silicon or semiconduct\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 19:37
S36	177	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 22:58
S37	177	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet or swt) near (metallic or metalic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 21:51
S38	664	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near4 (semiconductor or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 21:54

S39	3	(selectiv\$4 near2 remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near2 (semiconductor or silicon or semiconduct\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 22:21
S40	1	"20040191157".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 22:21
S41	199479	mosfet or (metal adj oxide adj semiconductor adj (fet or field)) or pmos or cmos or nmos or misfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 22:22
S42	0	"20040191157".pn. and (mosfet or (metal adj oxide adj semiconductor adj (fet or field)) or pmos or cmos or nmos or misfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 22:23
S43	0	"20040191157".pn. and (transistor or fet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 22:23
S44	7	((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic)) same (current or voltage) same (dissolv\$4 or burn or destroy\$4 or remov\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 23:00
S45	7	(((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic)) same (current or voltage) same (dissolv\$4 or burn or destroy\$4 or remov\$4)) and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/05 23:00
S84	63204	nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:53

S85	3340939	metal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 15:59
S86	2007544	semiconductor or silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 15:59
S87	345	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:53
S88	205	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:53
S89	212	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:53
S90	49	(dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metalic)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:54
S91	63204	nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:46
S92	345	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:53
S93	205	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:21

S94	212	(nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metalic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:21
S95	62	(dissolv\$4 or etch\$4 or remov\$4) with (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near4 (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 17:55
S96	28	(dissolv\$4 or etch\$4 or remov\$4) with (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near2 (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:48
S97	24	S96 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:21
S98	498	(nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metal metallic or metalic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:21
S99	235	(nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or si!)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:21
S10 0	53	S98 and S99 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:51
S10 1	13	(dissolv\$4 or etch\$4 or remov\$4 obliterated\$6 strip\$6 extract\$4 eradicated\$4 expunged\$6 annihilated\$4 destroyed\$4 break-up break adj up disband\$4 dispers\$4 liquify\$4) near4 (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near2 (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:54
S10 2	6	S101 and S98 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:55

S10 3	36	(dissolv\$4 or etch\$4 or remov\$4 obliterat\$6 strip\$6 extract\$4 eradicate\$4 expung\$6 annihilat\$4 destroy\$4 break-up break adj up disband\$4 dispers\$4 liquify\$4) with (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near2 (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:47
S10 4	8	S103 and S98 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:25
S10 5	2	S104 not S102	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:55
S10 6	14	(acid\$6 energy photon\$4 hf hydrofluor\$4 hydro adj fluor\$4) with (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near2 (semiconductor or silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:57
S10 7	5	S106 and S98 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 18:57
S10 8	13	(protect\$4 shield\$4 guard\$4 bulwark\$4 cover\$4 safeguard\$4 screen\$4 conserv\$4 perserv\$4 sav\$4 harbor\$4 shelter\$4) with S98	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:24
S10 9	1	S108 and S99 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:31
S11 0	13	S108 and (@ad < "20031017")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:31
S11 1	12	S110 not S109	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:32

S11 2	45932	ibm.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:46
S11 3	40	S91 and S112	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:47
S11 4	51823	(international adj business adj machines).as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:47
S11 5	1649	S91 and (S112 S114)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:48
S11 6	3118	(dissolv\$4 or etch\$4 or remov\$4 obliterat\$6 strip\$6 extract\$4 eradicat\$4 expung\$6 annihilat\$4 destroy\$4 break-up break adj up disband\$4 dispers\$4 liquify\$4) with (((nanotube or nt or cnt or swnt or snt or ntft or cntft or swntft or sntft)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:47
S11 7	36	S116 and (S112 S114)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 19:49